

SUPPORTING INFORMATION

**VISCOELASTIC CHARACTERIZATION OF BENZO-CROWN ETHER
FUNCTIONALISED ELECTROACTIVE FILMS**

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Theory for acoustic resonator responses of individual physical components

Previous work quantifies the surface mechanical impedance contributions of individual components of the electrochemical system¹⁻³. That for a semi-infinite Newtonian fluid (the electrolyte solution) is defined by its density (ρ_s) and viscosity (η)¹:

$$Z_L = \left(\frac{\omega \rho_s \eta}{2} \right)^{1/2} (1 + j) \quad (S1)$$

The contribution for a “rigid” (strictly, acoustically thin) mass layer, is defined in terms of the mass per unit area (areal density, ρ_m) and resonator angular frequency (ω)¹:

$$Z_m = j\omega\rho_m \quad (S2)$$

For a viscoelastic film, the contribution is expressed in terms of its thickness (h_f), shear modulus (G) and density (ρ_f)⁴:

$$Z_f = (G\rho_f)^{1/2} \tanh(\gamma h_f) \quad (S3)$$

where the shear modulus comprises real and imaginary components:

$$G = G' + jG'' \quad (S4)$$

associated with energy storage and loss, and the wave propagation constant:

$$\gamma = j\omega(\rho_f / G)^{1/2} \quad (S5)$$

The decay length of the acoustic wave within the film:

$$\delta = \frac{1}{\omega\sqrt{\rho_f}} \sqrt{\frac{2|G|}{1 - G'/|G|}} \quad (S6)$$

When $h_f > 2\delta$, there is negligible acoustic displacement at the outer film interface. The film is described as semi-infinite and the resonator response is insensitive to h_f . The hyperbolic tangent in Eqn. (S3) approaches unity and the film impedance reduces to a material (thickness independent) property, the characteristic mechanical impedance:

$$Z_0 = (G\rho_f)^{1/2} \quad (S7)$$

Figure S1: Admittance spectra acquired during the polymerisation of [Ni(3-Mesalophen-b15-c5)], *film B*. Scan rate: 20 mV s⁻¹. — Bare quartz/Au in deposition solution; — quartz/Au/polymer at the end of successive deposition cycles (arrow indicates time sequence).

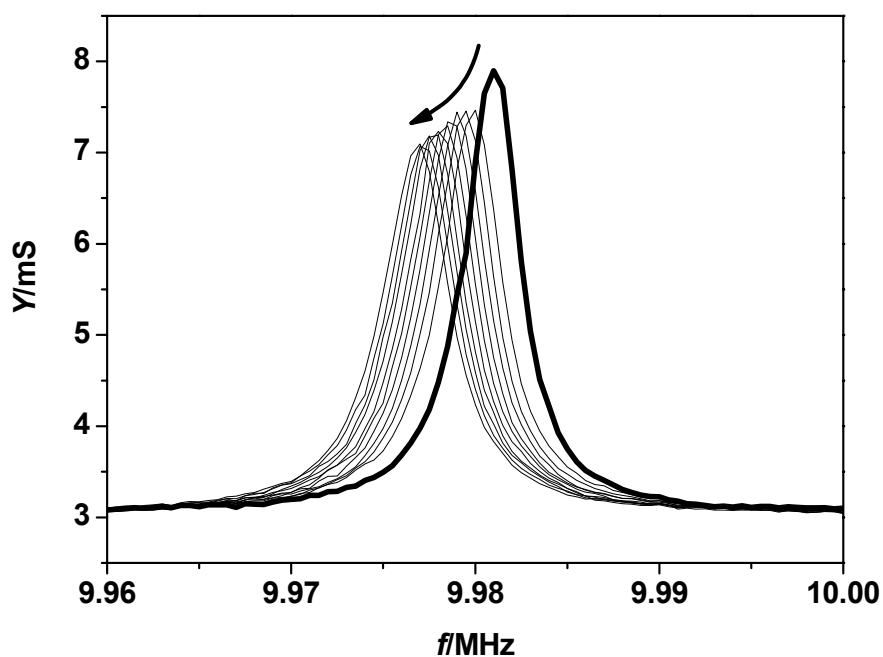


Figure S2: Analysis of acoustic resonator response during polymerisation of [Ni(3-Mesalophen-b15-c5)], to form films **A** (■) and **B** (●). Panel a: variation of resonant frequency change (with respect to that of bare electrode in solution) with deposition charge (Q_{dep}). Lines are least squares fits. Panel b: variation of resonant admittance with resonant frequency change.

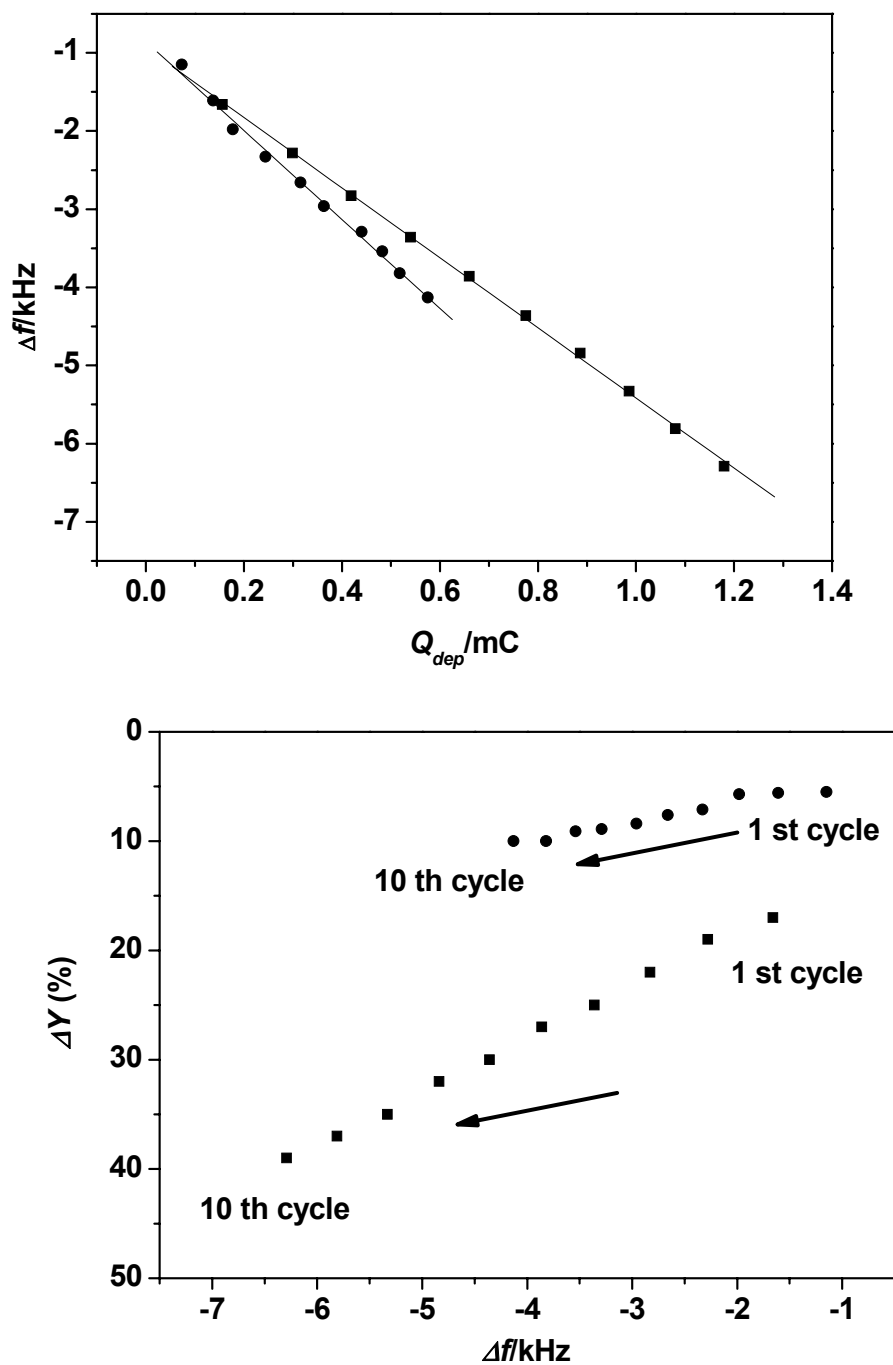
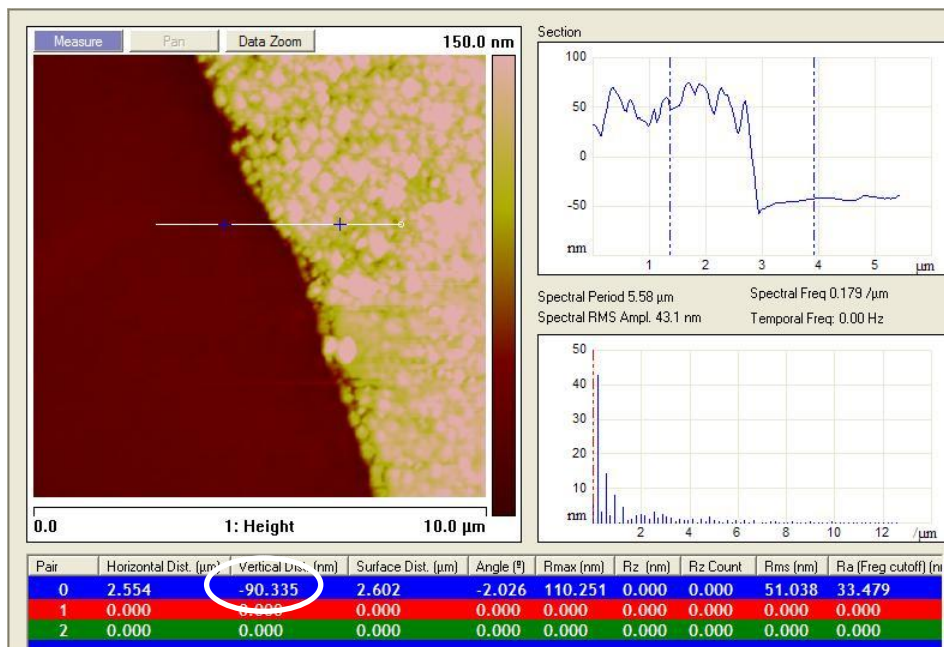
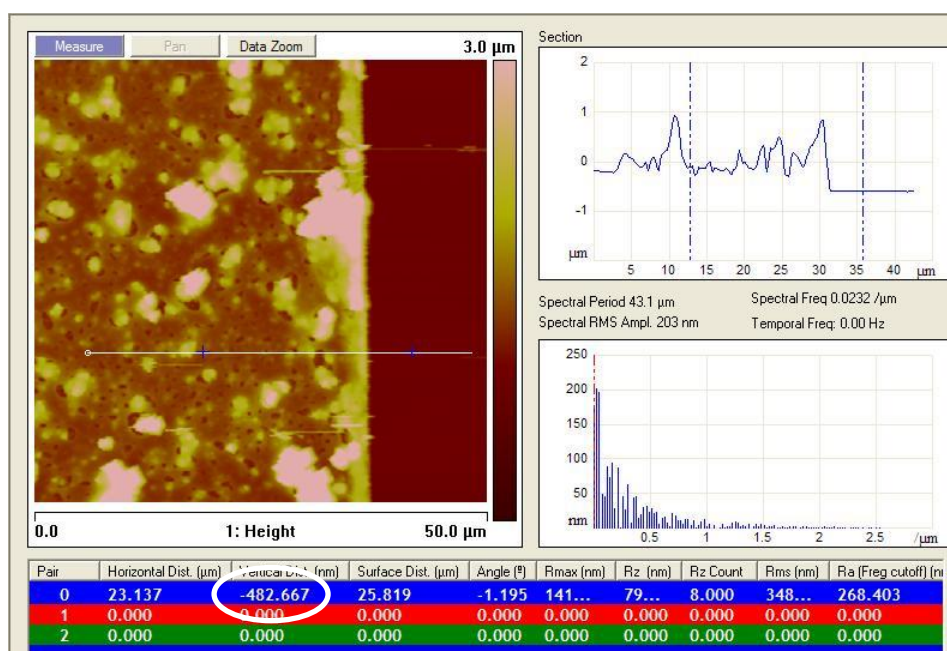


Figure S3: AFM images used to estimate h_f at cut edges of films **E** (panel a) and **F** (panel b).

a



b



References

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